

Supporting Information

Solution-processable star-shaped small molecules for efficient organic RRAM by induced conductive filament mechanism

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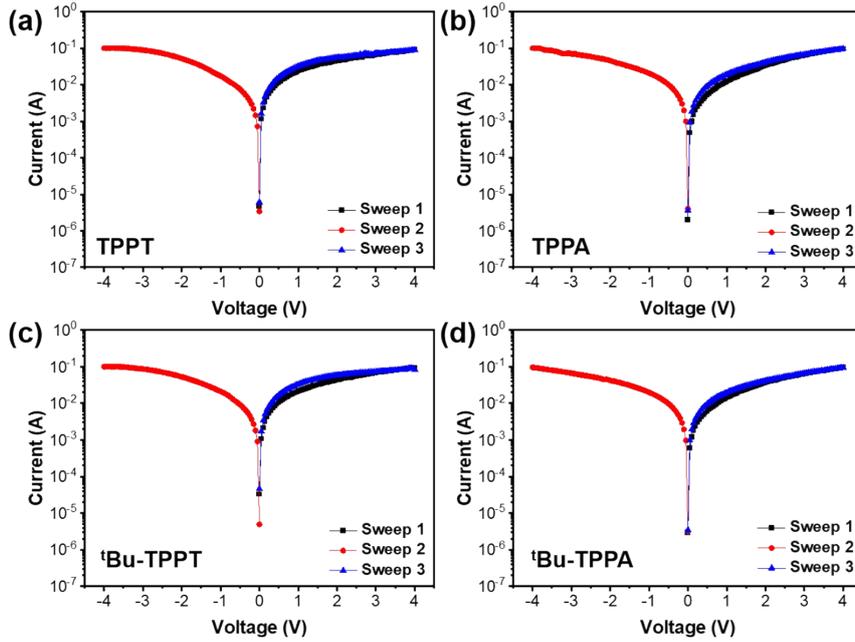


Fig. S1 Retested I–V curves of all memory devices after a period of one-month for (a) TPPT, (b) TPPA, (c) ^tBu-TPPT and (d) ^tBu-TPPA, respectively.

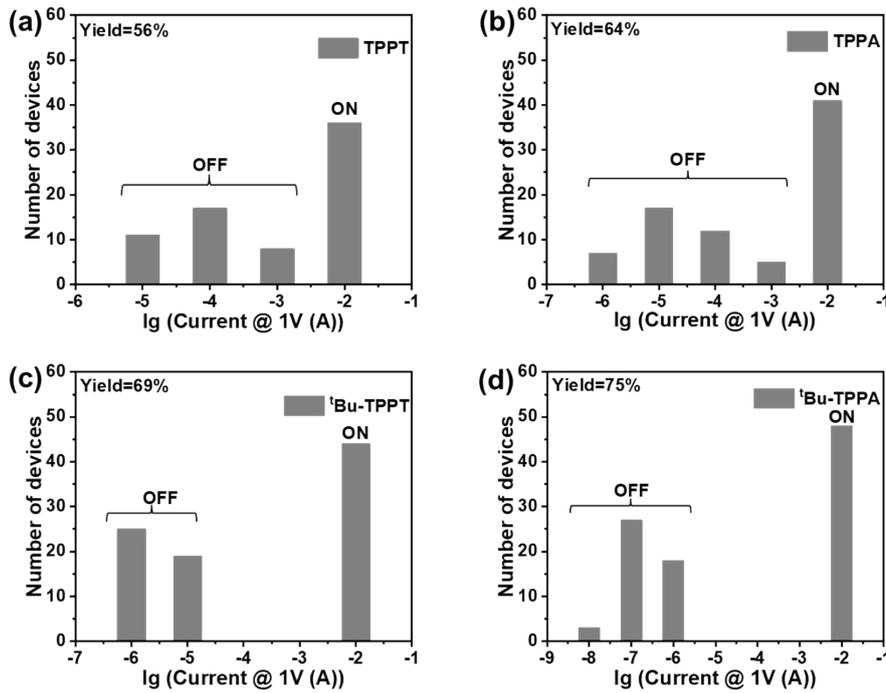


Fig. S2 The statistical analysis of the data of reproducibility and current distribution of devices based on (a)TPPT, (b)TPPA, (c) ^tBu-TPPT, and (d) ^tBu-TPPA (64 cells for each device).

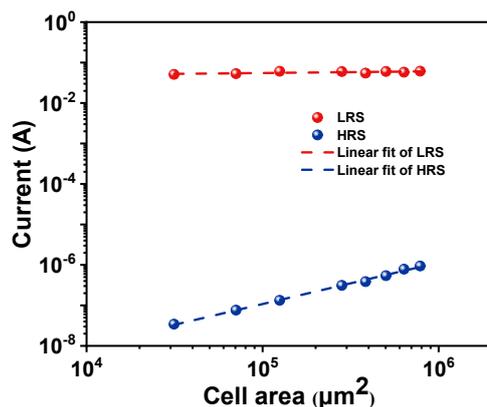


Fig. S3 The relationship of cell area and current in LRS (red) and HRS (blue), respectively (Insert is the photo of as-fabricated mask-type device).

Table S1 The photophysical properties for BPPT, TPPT, TPPA, ^tBu-TPPT and ^tBu-TPPA.

Molecules		BPPT	TPPT	TPPA	^t Bu-TPPT	^t Bu-TPPA
λ_{abs} (nm)	Solution	310	334	273/367	347	278/368
	Film	310	335	277/371	349	300/389

Table S2 Photophysical and electrochemical properties of BPPT, TPPT, TPPA, ^tBu-TPPT and ^tBu-TPPA.

Molecules	$\lambda_{\text{onset}}^{\text{a}}$ (nm)	E_{ox}^{b} (V)	E_{g}^{c} (eV)	HOMO ^d (eV)	LUMO ^d (eV)
BPPT	344	1.45	3.60	-5.93	-2.33
TPPT	374	1.41	3.32	-5.89	-2.57
^tBu-TPPT	383	1.60	3.24	-6.08	-2.84
TPPA	400	0.86	3.10	-5.34	-2.24
^tBu-TPPA	403	0.91	3.07	-5.39	-2.32

^a THF measurement.

^b Calculated using CV.

^c Calculated from onset of the absorption spectra ($E_{\text{g}} = 1240/\lambda_{\text{onset}}$).

^d The HOMO and LUMO energy levels measured against ferrocene were calculated using the following equations: $E_{\text{HOMO}} = [E_{\text{ox}} - E_{\text{Fc}} + 4.8]$, $E_{\text{LUMO}} = [E_{\text{HOMO}} - E_{\text{g}}]$.

Table S3 Statistic results of the star-shaped molecules-based memory devices.

Devices	BPPT	TPPT	TPPA	^tBu-TPPT	^tBu-TPPA
V_{th}(V)	–	1.60	1.50	1.50	1.45
I_{ON}/I_{OFF}	–	10 ² :1	10 ³ :1	10 ⁴ :1	10 ⁵ :1